8212
8-BIT INPUT/OUTPUT PORT

- **Fully Parallel 8-Bit Data Register and Buffer**
- **Service Request Flip-Flop for Interrupt Generation**
- **Low Input Load Current — .25mA Max.**
- **Three State Outputs**
- **Outputs Sink 15mA**
- **3.65V Output High Voltage for Direct Interface to 8008, 8080A, or 8085A CPU**
- **Asynchronous Register Clear**
- **Replaces Buffers, Latches and Multiplexers in Microcomputer Systems**
- **Reduces System Package Count**

The 8212 input/output port consists of an 8-bit latch with 3-state output buffers along with control and device selection logic. Also included is a service request flip-flop for the generation and control of interrupts to the microprocessor.

The device is multimode in nature. It can be used to implement latches, gated buffers or multiplexers. Thus, all of the principal peripheral and input/output functions of a microcomputer system can be implemented with this device.

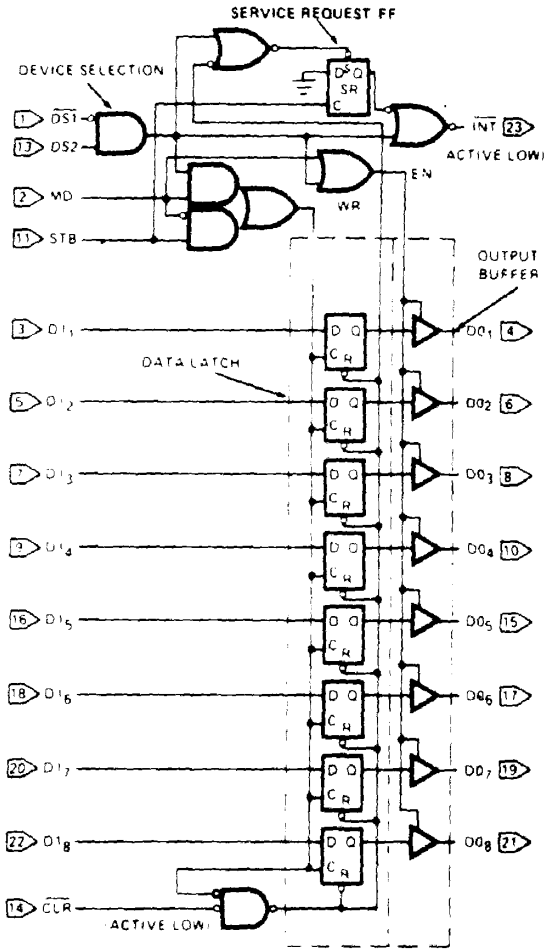
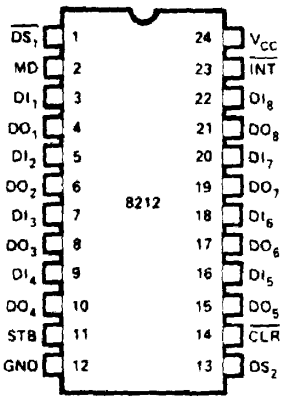


Figure 1. Logic Diagram



DI_1-DI_8	DATA IN
DO_1-DO_8	DATA OUT
$\overline{DS_1}$, DS_2	DEVICE SELECT
MD	MODE
STB	STROBE
INT	INTERRUPT (ACTIVE LOW)
CLR	CLEAR (ACTIVE LOW)

Figure 2. Pin Configuration

FUNCTIONAL DESCRIPTION

Data Latch

The 8 flip-flops that make up the data latch are of a "D" type design. The output (Q) of the flip-flop will follow the data input (D) while the clock input (C) is high. Latching will occur when the clock (C) returns low.

The latched data is cleared by an asynchronous reset input ($\overline{CLR}$). (Note: Clock (C) Overrides Reset ($\overline{CLR}$).)

Output Buffer

The outputs of the data latch (Q) are connected to 3-state, non-inverting output buffers. These buffers have a common control line (EN); this control line either enables the buffer to transmit the data from the outputs of the data latch (Q) or disables the buffer, forcing the output into a high impedance state. (3-state)

The high-impedance state allows the designer to connect the 8212 directly onto the microprocessor bi-directional data bus.

Control Logic

The 8212 has control inputs $\overline{DS1}$, DS2, MD and STB. These inputs are used to control device selection, data latching, output buffer state and service request flip-flop.

$\overline{DS1}$, DS2 (Device Select)

These 2 inputs are used for device selection. When $\overline{DS1}$ is low and DS2 is high ($\overline{DS1} \cdot DS2$) the device is selected. In the selected state the output buffer is enabled and the service request flip-flop (SR) is asynchronously set.

MD (Mode)

This input is used to control the state of the output buffer and to determine the source of the clock input (C) to the data latch.

When MD is high (output mode) the output buffers are enabled and the source of clock (C) to the data latch is from the device selection logic ($\overline{DS1} \cdot DS2$).

When MD is low (input mode) the output buffer state is determined by the device selection logic ($\overline{DS1} \cdot DS2$) and the source of clock (C) to the data latch is the STB (Strobe) input.

STB (Strobe)

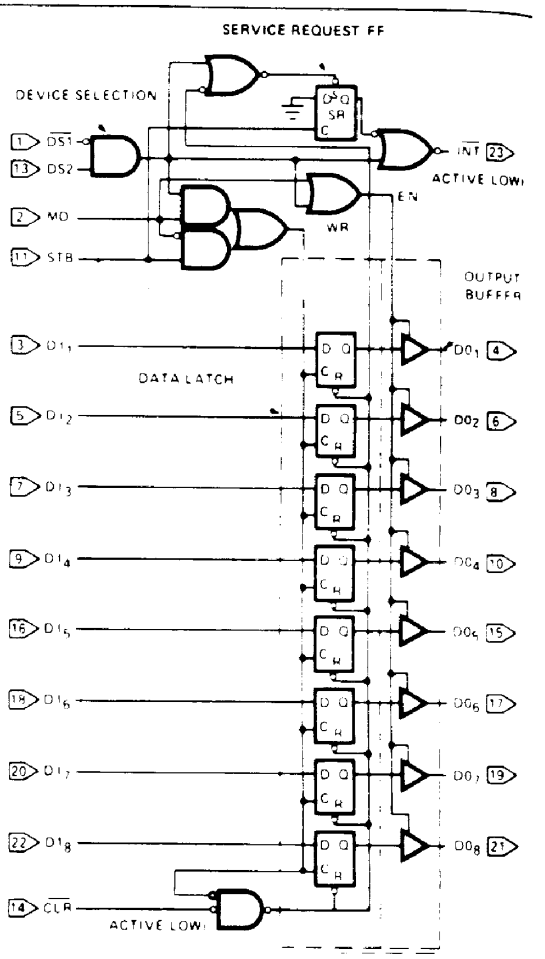
This input is used as the clock (C) to the data latch for the input mode MD = 0) and to synchronously reset the service request flip-flop (SR).

Note that the SR flip-flop is negative edge triggered.

Service Request Flip-Flop

The (SR) flip-flop is used to generate and control interrupts in microcomputer systems. It is asynchronously set by the $\overline{CLR}$ input (active low). When the (SR) flip-flop is set it is in the non-interrupting state.

The output of the (SR) flip-flop (Q) is connected to an inverting input of a "NOR" gate. The other input to the "NOR" gate is non-inverting and is connected to the device selection logic ($\overline{DS1} \cdot DS2$). The output of the "NOR" gate ($\overline{INT}$) is active low (interrupting state) for connection to active low input priority generating circuits.



STB	MD	(DS_1 DS_2)	DATA OUT EQUALS
0	0	0	3 STATE
1	0	0	3 STATE
0	1	0	DATA LATCH
1	1	0	DATA LATCH
0	0	1	DATA LATCH
↑	0	1	DATA IN
0	1	1	DATA IN
1	1	↑	DATA IN

$\overline{CLR}$ - RESETS DATA LATCH
SETS SR FLIP FLOP
(NO EFFECT ON OUTPUT BUFFER)

CLR	($\overline{DS_1}$ DS_2)	STB	*SR	INT
0	0	0	1	1
0	1	0	1	0
1	1	↘	0	0
1	1	0	1	0
1	0	0	1	1
1	1	↘	1	0

*INTERNAL SR FLIP FLOP

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias Plastic ..... 0°C to +70°C
Storage Temperature ..... -65°C to +160°C
All Output or Supply Voltages ..... -0.5 to +7 Volts
All Input Voltages ..... -1.0 to 5.5 Volts
Output Currents 100mA

NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

D.C. CHARACTERISTICS (T_A=0°C to +75°C, V_{CC}= +5V ± 5%)

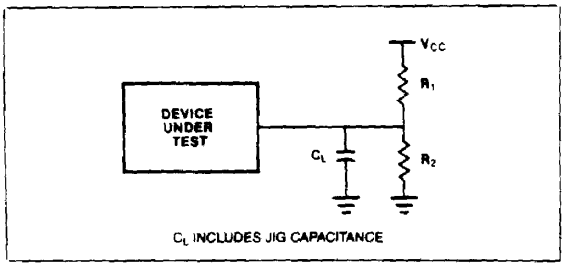
Symbol	Parameter	Limits			Unit	Test Conditions
		Min.	Typ.	Max.		
I_F	Input Load Current, ACK, DS_2, CR, DI_1-DI_8 Inputs			-.25	mA	V_F = .45V
I_F	Input Load Current MD Input			-.75	mA	V_F = .45V
I_F	Input Load Current DS_1 Input			-1.0	mA	V_F = .45V
I_R	Input Leakage Current, ACK, DS, CR, DI_1-DI_8 Inputs			10	µA	$V_R \leq V_{CC}$
I_R	Input Leakage Current MO Input			30	µA	$V_R \leq V_{CC}$
I_R	Input Leakage Current DS_1 Input			40	µA	$V_R \leq V_{CC}$
V_C	Input Forward Voltage Clamp			-1	V	I_C = -5mA
V_{IL}	Input "Low" Voltage			.85	V	
V_{IH}	Input "High" Voltage	2.0			V	
V_{OL}	Output "Low" Voltage			.45	V	I_{OL} = 15mA
V_{OH}	Output "High" Voltage	3.65	4.0		V	I_{OH} = -1mA
I_{SC}	Short Circuit Output Current	-15		-75	mA	V_O = 0V, V_{CC} = 5V
$\|I_{IO}\|$	Output Leakage Current High Impedance State			20	µA	V_O = .45V/5.25V
I_{CC}	Power Supply Current		90	130	mA	

CAPACITANCE* (F = 1MHz, V_{BIAS} = 2.5V, V_{CC} = +5V, T_A = 25°C)

Symbol	Test	Limits	
		Typ.	Max.
C_{IN}	DS_1 MD Input Capacitance	9pF	12pF
C_{IN}	DS_2, $\overline{CLR}$, STB, DI_1-DI_8 Input Capacitance	5pF	9pF
C_{OUT}	DO_1-DO_8 Output Capacitance	8pF	12pF

*This parameter is sampled and not 100% tested.

A.C. TESTING LOAD CIRCUIT



SWITCHING CHARACTERISTICS

Conditions of Test

Input Pulse Amplitude = 2.5V
Input Rise and Fall Times 5ns
Between 1V and 2V Measurements made at 1.5V
with 15mA and 30pF Test Load

NOTE:

1.

Test	C_L*	R_1	R_2
t_{PD}, t_{WE}, t_R, t_S, t_C	30pF	300Ω	600Ω
t_E, ENABLE↑	30pF	10KΩ	1KΩ
t_E, ENABLE↓	30pF	300Ω	600Ω
t_E, DISABLE↑	5pF	300Ω	600Ω
t_E, DISABLE↓	5pF	10KΩ	1KΩ

*Includes probe and jig capacitance.

A.C. CHARACTERISTICS (T_A = 0°C to +70°C, V_{CC} = +5V ± 5%)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min.	Typ.	Max.		
t_{PW}	Pulse Width	30			ns	
t_{PD}	Data to Output Delay			30	ns	Note 1
t_{WE}	Write Enable to Output Delay			40	ns	Note 1
t_{SET}	Data Set Up Time	15			ns	
t_H	Data Hold Time	20			ns	
t_R	Reset to Output Delay			40	ns	Note 1
t_S	Set to Output Delay			30	ns	Note 1
t_E	Output Enable/Disable Time			45	ns	Note 1
t_C	Clear to Output Delay			55	ns	Note 1

APPLICATIONS

Basic Schematic Symbols

Two examples of ways to draw the 8212 on system schematics—(1) the top being the detailed view showing pin numbers, and (2) the bottom being the symbolic view showing the system input or output as a system bus (bus containing 8 parallel lines). The output to the data bus is symbolic in referencing 8 parallel lines.

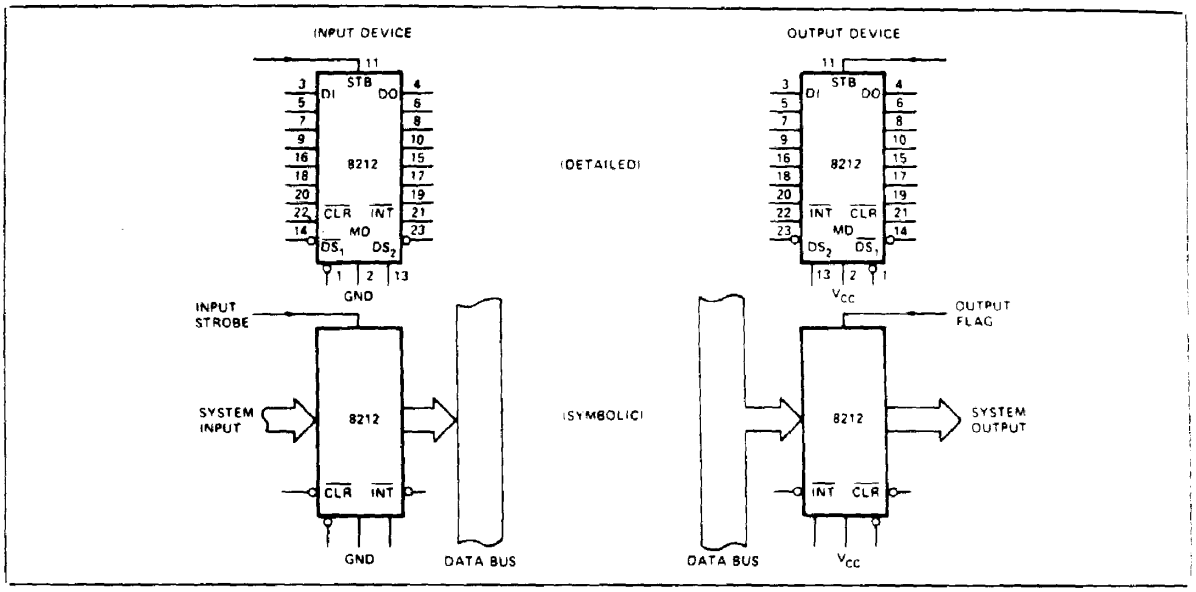


Figure 3. Basic Schematic Symbols

Gated Buffer (3-State)

The simplest use of the 8212 is that of a gated buffer. By tying the mode signal low and the strobe input high, the data latch is acting as a straight through gate. The output buffers are then enabled from the device selection logic $\overline{DS1}$ and DS2.

When the device selection logic is false, the outputs are 3-state.

When the device selection logic is true, the input data from the system is directly transferred to the output. The input data load is 250 micro amps. The output data can sink 15 milli amps. The minimum high output is 3.65 volts.

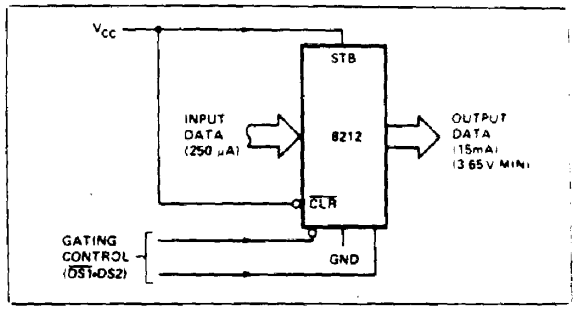


Figure 4. Gated Buffer